

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
JAWARANI, DHARMESH

Patent No.: 7262105 B2

Application No.: 10/718892

Issue Date: 4/4/2006

Filed: 11-21-2003

Examiner: Carl Whitehead, Jr.

Group Art Unit: 2813

Title: SEMICONDUCTOR DEVICE WITH SILICIDED SOURCE/DRAINS

Certificate of Submission

I hereby certify that this correspondence is being submitted to the USPTO, Alexandria, VA.

Addressed per C.F.R. § 1.1(a) and deposited with the United States Postal Service with sufficient postage as first class mail.

Facsimile transmitted in accordance with C.F.R. §1.6(d).

Submitted electronically via EFS in accordance with "Legal Framework for EFS Web".

February 26, 2008
Date of Submission

Teresa Shephard
Signature

Teresa Shephard
Printed Name of Person Signing Certificate

Commissioner for Patents
Alexandria, VA 22313

SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent. Please enter these corrections. Since the error(s) appear to be on the part of the Applicant, the required fee will be charged to Deposit Account 503079 via the Electronic Filing System.

Respectfully submitted,

Feb 25, 2008
Date

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CERTIFICATE OF CORRECTION

Page 1 of 1

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FIRST NAMED INVENTOR: JAWARANI, DHARMESH

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

In Column 5, Line 38, Claim No. 9:

Change "implanting the is" to --implanting the germanium is—

In Column 5, Line 64, Claim No. 16:

Remove "partieles"

In Column 6, Line 3, Claim No. 17:

Change "implanting of the further includes" to—implanting of the germanium further includes--

MAILING ADDRESS OF SENDER (Please do not use customer number below)

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Law Department

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